

SSM6N25TU

High Speed Switching Applications

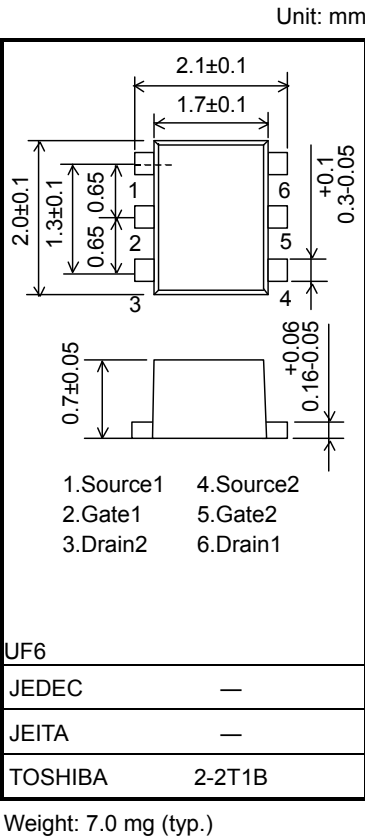
- Optimum for high-density mounting in small packages
- Low on-resistance:      $R_{on} = 395m\Omega$  (max) (@ $V_{GS} = 1.8\text{ V}$ )  
                                  $R_{on} = 190m\Omega$  (max) (@ $V_{GS} = 2.5\text{ V}$ )  
                                  $R_{on} = 145m\Omega$  (max) (@ $V_{GS} = 4.0\text{ V}$ )

Absolute Maximum Ratings (Ta = 25°C)  
(Q1, Q2 Common)

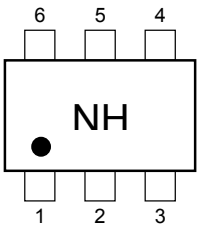
Characteristics		Symbol	Rating	Unit
Drain-Source voltage		$V_{DS}$	20	V
Gate-Source voltage		$V_{GSS}$	$\pm 12$	V
Drain current	DC	$I_D$	0.5	A
	Pulse	$I_{DP}$	1.5	
Drain power dissipation		$P_D$ (Note 1)	500	mW
Channel temperature		$T_{ch}$	150	°C
Storage temperature range		$T_{stg}$	-55~150	°C

Note:    Using continuously under heavy loads (e.g. the application of high temperature/current/voltage and the significant change in temperature, etc.) may cause this product to decrease in the reliability significantly even if the operating conditions (i.e. operating temperature/current/voltage, etc.) are within the absolute maximum ratings.  
Please design the appropriate reliability upon reviewing the Toshiba Semiconductor Reliability Handbook (“Handling Precautions”/“Derating Concept and Methods”) and individual reliability data (i.e. reliability test report and estimated failure rate, etc).

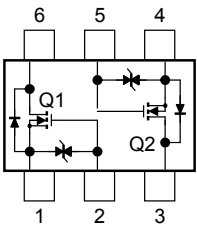
Note 1: Mounted on FR4 board. (total dissipation)  
(25.4 mm × 25.4 mm × 1.6 t, Cu Pad: 645 mm<sup>2</sup>)



Marking



Equivalent Circuit (top view)



Handling Precaution

When handling individual devices (which are not yet mounted on a circuit board), be sure that the environment is protected against electrostatic electricity. Operators should wear anti-static clothing, and containers and other objects that come into direct contact with devices should be made of anti-static materials.

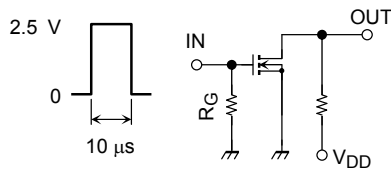
## Electrical Characteristics (Ta = 25°C) (Q1, Q2 Common)

Characteristics	Symbol	Test Condition	Min	Typ.	Max	Unit
Gate leakage current	$I_{GSS}$	$V_{GS} = \pm 12V, V_{DS} = 0$	—	—	$\pm 1$	$\mu A$
Drain-Source breakdown voltage	$V_{(BR) DSS}$	$I_D = 1 mA, V_{GS} = 0$	20	—	—	V
	$V_{(BR) DSX}$	$I_D = 1 mA, V_{GS} = -12 V$	10	—	—	
Drain cut-off current	$I_{DSS}$	$V_{DS} = 20 V, V_{GS} = 0$	—	—	1	$\mu A$
Gate threshold voltage	$V_{th}$	$V_{DS} = 3 V, I_D = 0.1 mA$	0.5	—	1.1	V
Forward transfer admittance	$ Y_{fs} $	$V_{DS} = 3 V, I_D = 0.25 A$ (Note2)	1.2	2.4	—	S
Drain-Source on-resistance	$R_{DS(ON)}$	$I_D = 0.25 A, V_{GS} = 4.0 V$ (Note2)	—	125	145	$m\Omega$
		$I_D = 0.25 A, V_{GS} = 2.5 V$ (Note2)	—	150	190	
		$I_D = 0.25 A, V_{GS} = 1.8 V$ (Note2)	—	200	395	
Input capacitance	$C_{iss}$	$V_{DS} = 10 V, V_{GS} = 0, f = 1 MHz$	—	268	—	pF
Reverse transfer capacitance	$C_{rss}$	$V_{DS} = 10 V, V_{GS} = 0, f = 1 MHz$	—	34	—	pF
Output capacitance	$C_{oss}$	$V_{DS} = 10 V, V_{GS} = 0, f = 1 MHz$	—	44	—	pF
Switching time	Turn-on time	$t_{on}$	—	11	—	ns
	Turn-off time	$t_{off}$		15		

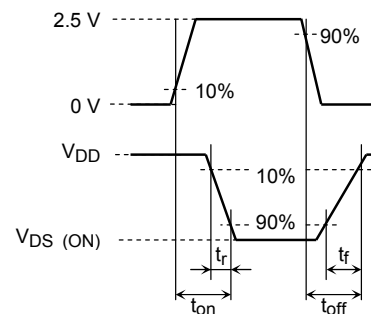
Note2: Pulse test

## Switching Time Test Circuit

## (a) Test Circuit



$V_{DD} = 10 V$   
 $R_G = 4.7 \Omega$   
 $D.U. \leq 1\%$   
 $V_{IN}: t_r, t_f < 5 ns$   
 Common Source  
 $T_a = 25^\circ C$

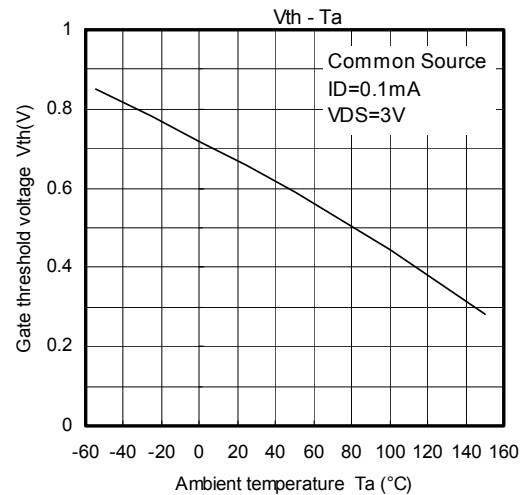
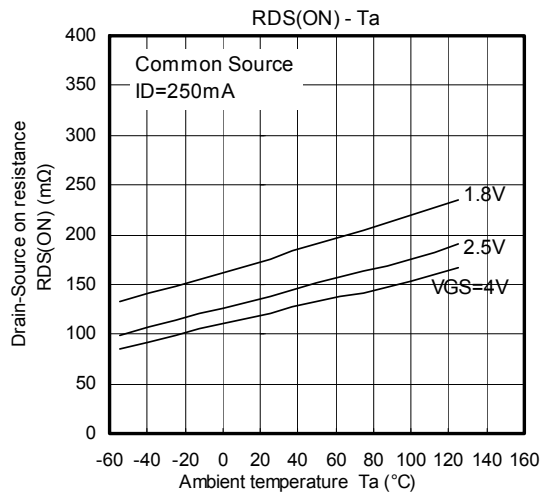
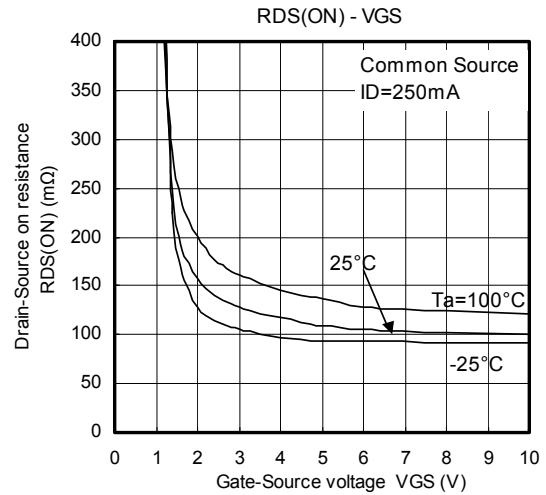
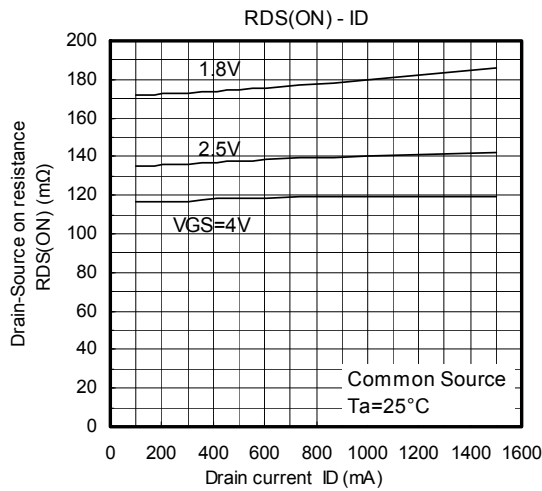
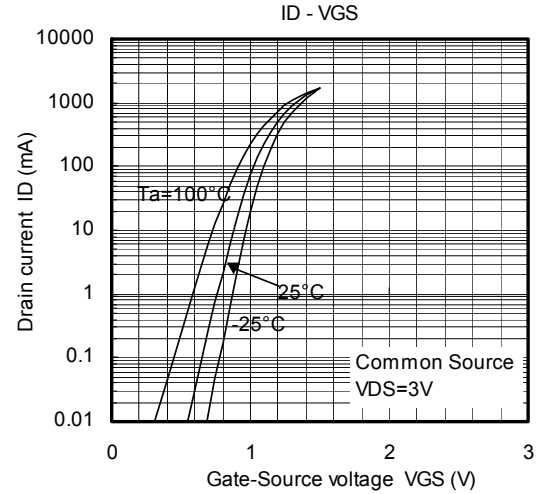
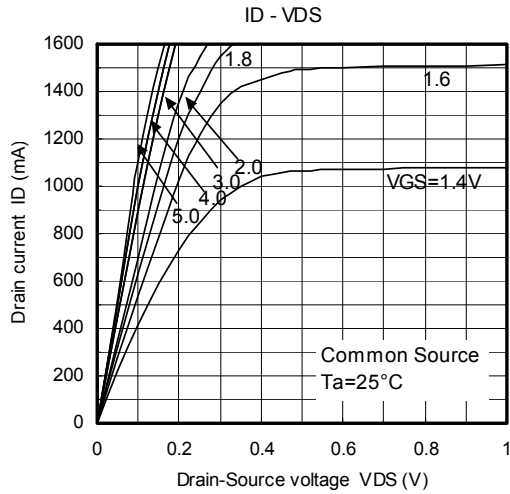
(b)  $V_{IN}$ (c)  $V_{OUT}$ 

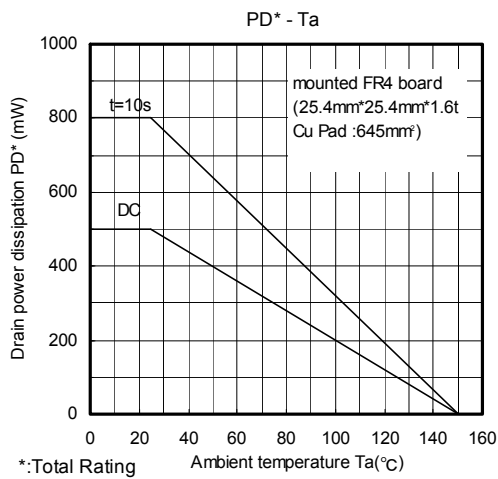
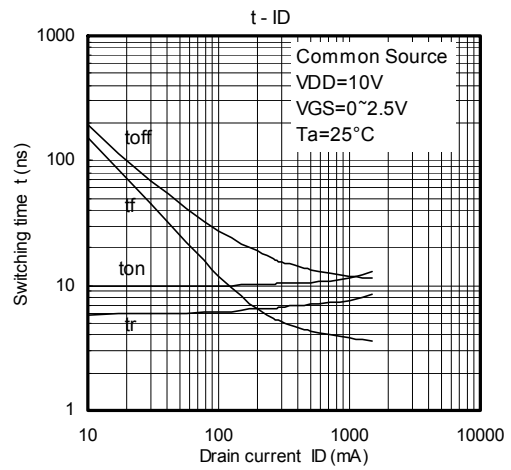
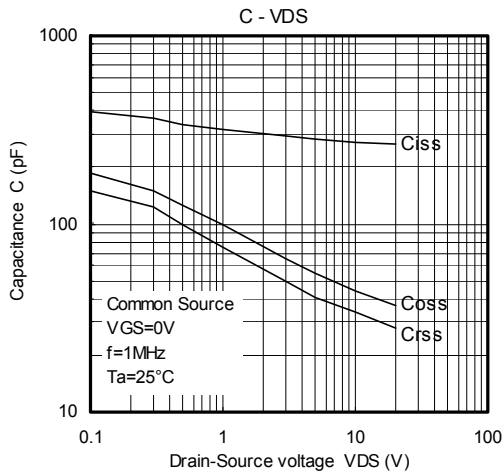
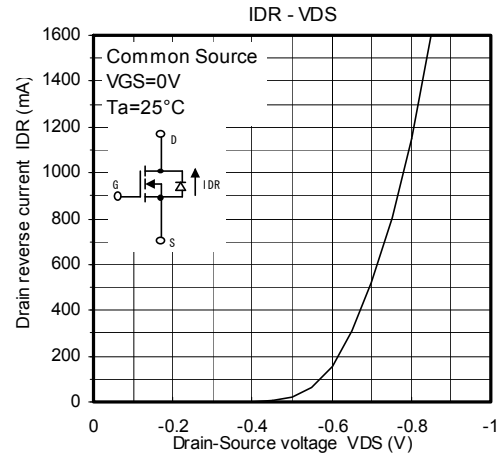
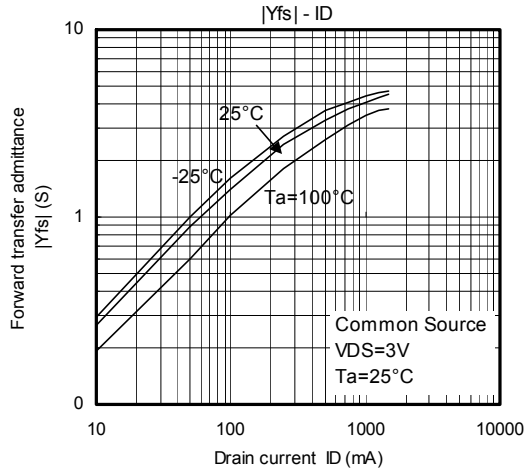
## Precaution

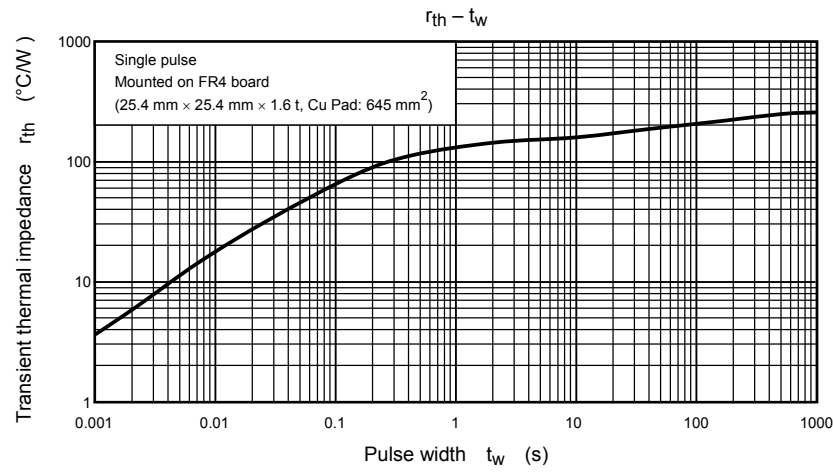
$V_{th}$  can be expressed as the voltage between gate and source when the low operating current value is  $I_D = 100 \mu A$  for this product. For normal switching operation,  $V_{GS(on)}$  requires a higher voltage than  $V_{th}$  and  $V_{GS(off)}$  requires a lower voltage than  $V_{th}$ .

(The relationship can be established as follows:  $V_{GS(off)} < V_{th} < V_{GS(on)}$ )

Please take this into consideration when using the device.









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20070701-EN GENERAL

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